



钜地半导体
Tudi Semiconductor

Product Specification

TUDI- SN74LVC1G125

Single Bus Buffer Gate With 3-State Output

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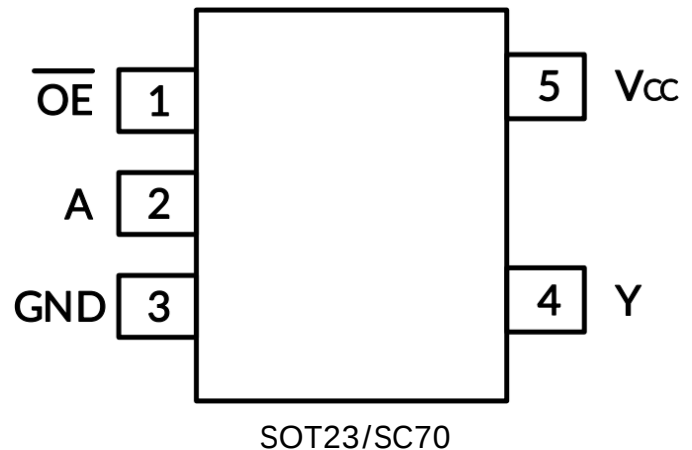
**semiconductor device
manufacturer**

- Design
- research and development
- production
- and sales



FEATURES

- Operating Voltage Range: 1.65V to 5.5V
- Low Power Consumption: 0.1 μ A (TYP)
- Operating Temperature Range:
-40 °C to 125 °C
- Inputs Accept Voltage to 5.5V
- ± 24 mA Output Drive at $V_{cc}=3.0$ V
- Latch-up Performance Exceeds 100mA
- Micro SIZE PACKAGES: SOT23-5, SC70-5



APPLICATIONS

- AV Receiver
- Cable Modem Termination Systems
- Digital Picture Frame (DPF)
- High-Speed Data Acquisition and Generation
- Motor Controls: High-Voltage
- Personal Navigation Device (GPS)
- Portable Media Player
- Video Communication Systems

DESCRIPTIONS

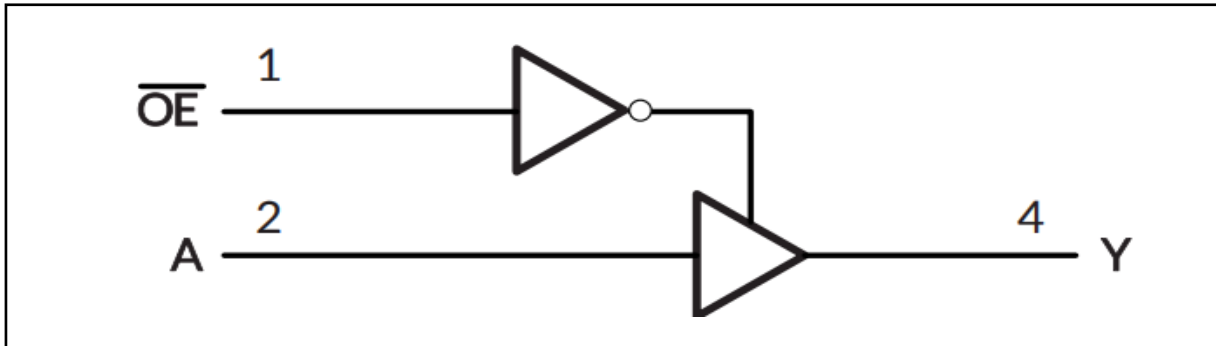
The single buffer is designed for 1.65V to 5.5V V_{cc} operation. The SN74LVC1G125 device is single line driver with 3-state output. The output is disabled when the output-enable (OE) input is high.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down, OE should be tied to V_{cc} through a pullup resistor, the minimum value of the resistor is determined by the current-sinking capability of the driver. The SN74LVC1G125 is available in Green SOT23-5 and SC70-5 packages. It operates over an ambient temperature range of -40 °C to 125 °C.



SIMPLIFIED SCHEMATIC



FUNCTION TABLE

INPUTS		OUTPUT
OE	A	Y
L	H	H
L	L	L
H	X	Z

H=HIGH Logic Level
L =LOW Logic Level
X=Don ' t Care
Z=High-impedance OFF-state

PIN CONFIGURATION AND FUNCTIONS (TOP VIEW)

PIN	NAME	I/O	FUNCTION
1	OE	I	OE Enable/Input
2	A	I	A Input
3	GND	-	Ground Pin
4	Y	O	Y Output
5	V _{cc}	-	Power Pin



Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1) (2)

		MIN	MAX	UNIT
V_{cc}	Supply voltage range	-0.5	6.5	V
V_i	Input voltage range ⁽²⁾	-0.5	6.5	V
V_o	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾	-0.5	6.5	V
V_o	Voltage range applied to any output in the high or low state ⁽²⁾⁽³⁾	-0.5	$V_{cc}+0.5$	V
I_{ik}	Input clamp current $V_i < 0$		-50	mA
I_{ok}	Output clamp current $V_o < 0$		-50	mA
I_o	Continuous output current		± 50	mA
	Continuous current through V_{cc} or GND		± 100	mA

Package Thermal Impedance

	PARAMETER	MIN	MAX	UNIT
θ_{JA}	Package thermal impedance(4)	SOT23-5 SC70-5	230 380	/W

Temperature

PARAMETER		MIN	MAX	UNIT
Temperature	Junction temperature, T_j (5)	-65	150	
	Storage temperature, T_{stg}	-65	150	



ESD Ratings

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

	VALUE	UNIT
Human-Body Model(HBM)	±4000	V
Charged-Device Model (CDM)	±1000	
Machine Model(MM)	±200	

ESD SENSITIVITY CAUTION



ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

NOTE:

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V_{CC} is provided in the Recommended Operating Conditions table.
- (4) The package thermal impedance is calculated in accordance with JEDEC-51.
- (5) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$, and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} - T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly onto a PCB.



ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (TYP values are at $T_A = +25^\circ\text{C}$, unless otherwise noted.)⁽¹⁾

Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
Supply voltage	V_{CC}	Operating Data retention only	1.65	5.5	V
			1.5	5.5	
High-level input voltage	V_{IH}	$V_{CC}=1.65\text{V to }1.95\text{V}$	$0.65 \times V_{CC}$		V
		$V_{CC}=2.3\text{V to }2.7\text{V}$	1.7		
		$V_{CC}=3\text{V to }3.6\text{V}$	2.2		
		$V_{CC}=4.5\text{V to }5.5\text{V}$	$0.7 \times V_{CC}$		
Low-level input voltage	V_{IL}	$V_{CC}=1.65\text{V to }1.95\text{V}$		$0.3 \times V_{CC}$	V
		$V_{CC}=2.3\text{V to }2.7\text{V}$		0.7	
		$V_{CC}=3\text{V to }3.6\text{V}$		0.8	
		$V_{CC}=4.5\text{V to }5.5\text{V}$		$0.3 \times V_{CC}$	
Input voltage	V_I		0	5.5	V
Output voltage	V_O		0	V_{CC}	V
Input transition rise or fall	t_r, t_f	$V_{CC}=1.8\text{V} \pm 0.15\text{V}, 2.5\text{V} \pm 0.2\text{V}$		20	ns/V
		$V_{CC}=3.3\text{V} \pm 0.3\text{V}$		10	
		$V_{CC}=5\text{V} \pm 0.5\text{V}$		5	
Operating temperature	T_A		-40	+125	



Electrical Characteristics

PARAMETER	TEST CONDITIONS	V _{cc}	TEMP	MIN	TYP	MAX	UNIT
V _{OH}	I _{OH} = -100μA	1.65V to 5.5V	Full	V _{cc} -0.1			V
	I _{OH} = -4mA	1.65V		1.2			
	I _{OH} = -8mA	2.3V		1.9			
	I _{OH} = -16mA	3V		2.4			
	I _{OH} = -24mA			2.3			
	I _{OH} = -32mA	4.5V		3.8			
V _{OL}	I _{OL} = 100μA	1.65V to 5.5V	Full			0.1	V
	I _{OL} = 4mA	1.65V				0.45	
	I _{OL} = 8mA	2.3V				0.3	
	I _{OL} = 16mA					0.4	
	I _{OL} = 24mA	3V				0.55	
	I _{OL} = 32mA	4.5V				0.55	
I _A or OE inputs	V _I = 5.5V or GND	0V to 5.5V	+25		± 0.1		μA
			Full			± 5	
I _{off}	V _I or V _O = 5.5V	0V	+25		± 0.1		μA
			Full			± 10	
I _{oz}	V _O = 0V to 5.5V	3.6V	Full			10	μA
I _{cc}	V _I = 5.5V or GND, I _O = 0	1.65V to 5.5V	+25		0.1		μA
			Full			10	
I _{cc}	One input at V _{cc} -0.6V, Other inputs at V _{cc} or GND	3V to 5.5V	Full			500	μA

Switching Characteristics, C_L = 30pF or 50pF

T_A = 25 °C

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{cc} = 1.8V ± 0.15V	V _{cc} = 2.5V ± 0.2V	V _{cc} = 3.3V ± 0.3V	V _{cc} = 5V ± 0.5V	UNIT
			TYP	TYP	TYP	TYP	
t _{pd}	A	Y	12	7	6	4.3	ns
t _{en}	OE	Y	14.9	7.8	6.5	4.8	ns
t _{dis}	OE	Y	11.4	7.4	5.7	5	ns



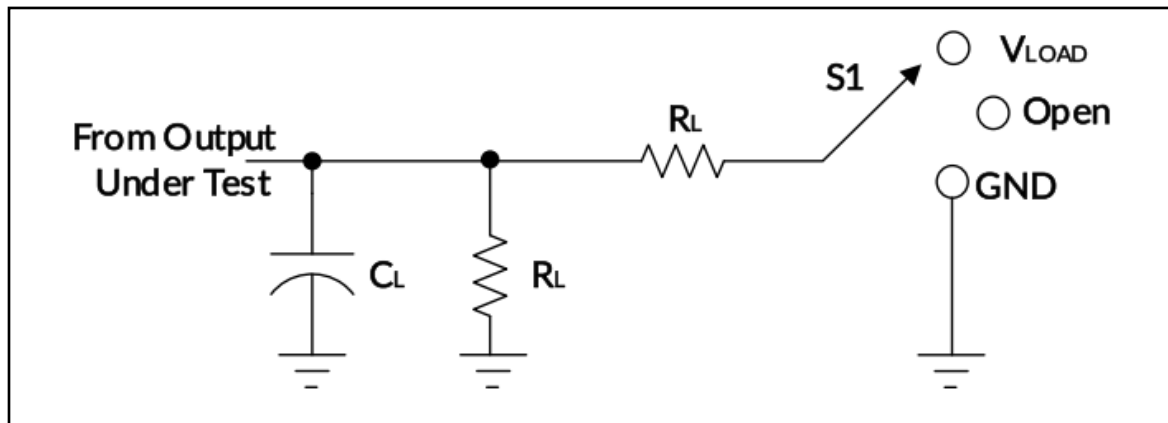
Operating Characteristics

$T_A = 25^\circ\text{C}$

	PARAMETER	TEST CONDITIONS	$V_{CC}=1.8\text{V}$	$V_{CC}=2.5\text{V}$	$V_{CC}=3.3\text{V}$	$V_{CC}=5\text{V}$	UNIT
			TYP	TYP	TYP	TYP	
C_{pd}	Power dissipation Output enabled	$f=10\text{MHz}$	18	18	19	21	pF
	capacitance Output disabled		2	2	2	4	

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

PARAMETER MEASUREMENT INFORMATION



TEST	S1
t_{pLH}/t_{pHL}	Open
t_{pLz}/t_{pZL}	V_{LOAD}
t_{pHz}/t_{pZH}	GND

V_{CC}	INPUTS		V_M	V_{LOAD}	C_L	R_L	V
	V_I	t_r/t_f					
$1.8\text{V} \pm 0.15\text{V}$	V_{CC}	$\leq 2\text{ns}$	$V_{CC}/2$	$2 \times V_{CC}$	30pF	1K Ω	0.15V
$2.5\text{V} \pm 0.2\text{V}$	V_{CC}	$\leq 2\text{ns}$	$V_{CC}/2$	$2 \times V_{CC}$	30pF	500 Ω	0.15V
$3.3\text{V} \pm 0.3\text{V}$	3V	$\leq 2.5\text{ns}$	1.5V	6V	50pF	500 Ω	0.3V
$5\text{V} \pm 0.5\text{V}$	V_{CC}	$\leq 2.5\text{ns}$	$V_{CC}/2$	$2 \times V_{CC}$	50pF	500 Ω	0.3V

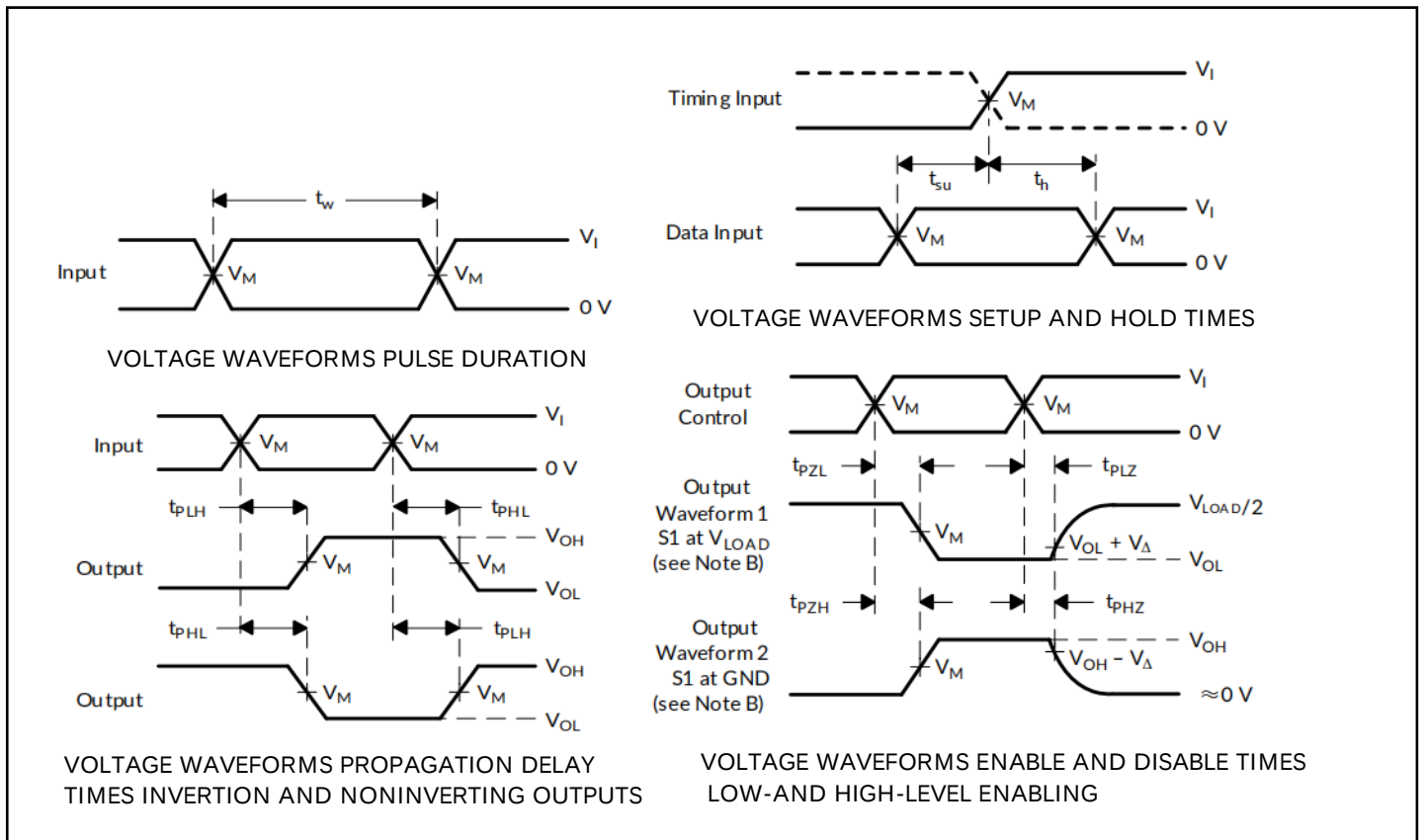


Figure 1. Load Circuit and Voltage Waveforms

NOTES: A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_o = 50 \Omega$.

D. The outputs are measured one at a time, with one transition per measurement.

E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .

F. t_{PZL} and t_{PZH} are the same as t_{en} .

G. t_{PLH} and t_{PHL} are the same as t_{pd} .

H. All parameters and waveforms are not applicable to all devices.



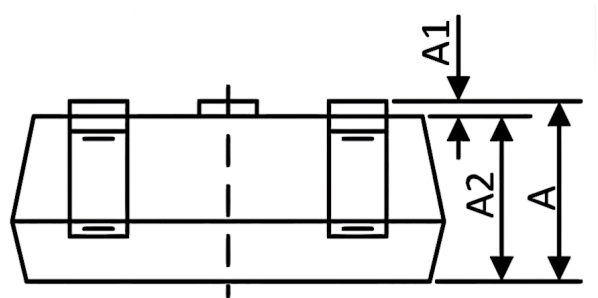
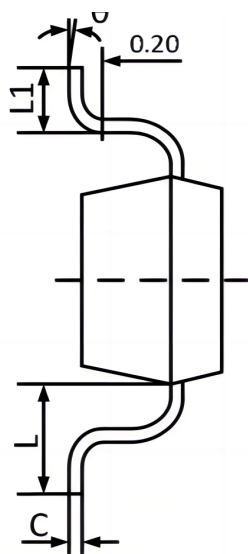
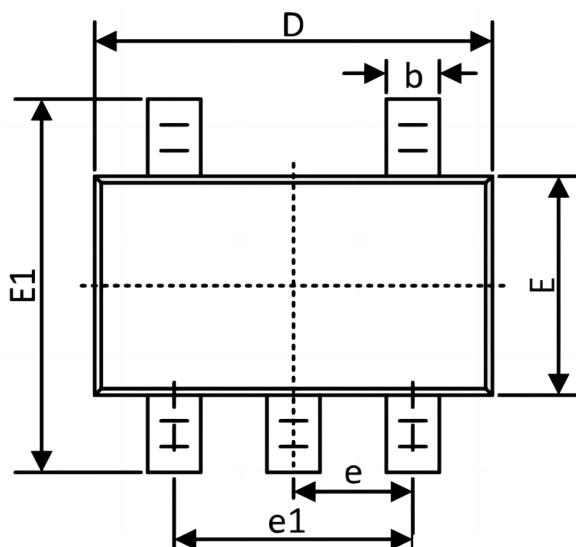
Order information

Order Number	Package	Package Quantity	Marking On The park	Temperature
SN74LVC1G125DCKR-TUDI	SC70-5	Tape,Reel,3000	CM5	-40°C~125°C
SN74LVC1G125DBVR-TUDI	SOT23-5	Tape,Reel,3000	C255	

Revision history

	Date	Revision	Page
V1.0	2018/6/6	New	1-13

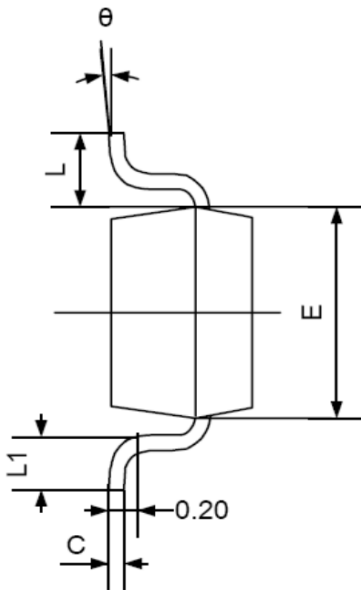
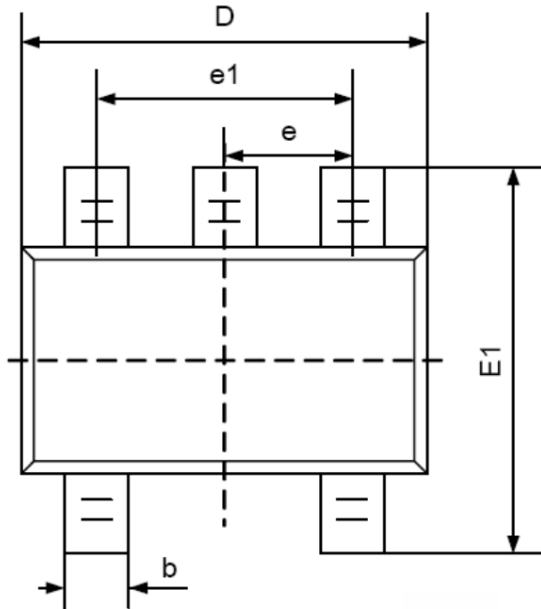
Package SOT23-5



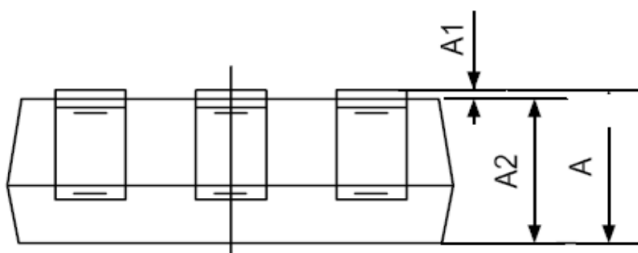
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.400	0.012	0.016
C	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.700REF		0.028REF	
L1	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°



Package SC70-5



Symbol	DimensionsIn Millimeters		DimensionsIn Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
C	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650TYP		0.026TYP	
e1	1.200	1.400	0.047	0.055
L	0.525REF		0.021REF	
L1	0.260	0.460	0.010	0.018
theta	0°	8°	0°	8°





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